

# ECE606: Solid State Devices

## Lecture 20: Electrostatics of p-n junction diodes

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# Outline

- 1) **Introduction to p-n junctions**
- 2) Drawing band-diagrams
- 3) Accurate solution in equilibrium
- 4) Band-diagram with applied bias

*Ref. Semiconductor Device Fundamentals, Chapter 5*

# What is a Diode good for ....

solar cells



GaAs lasers



Organic LED



Avalanche Photodiode

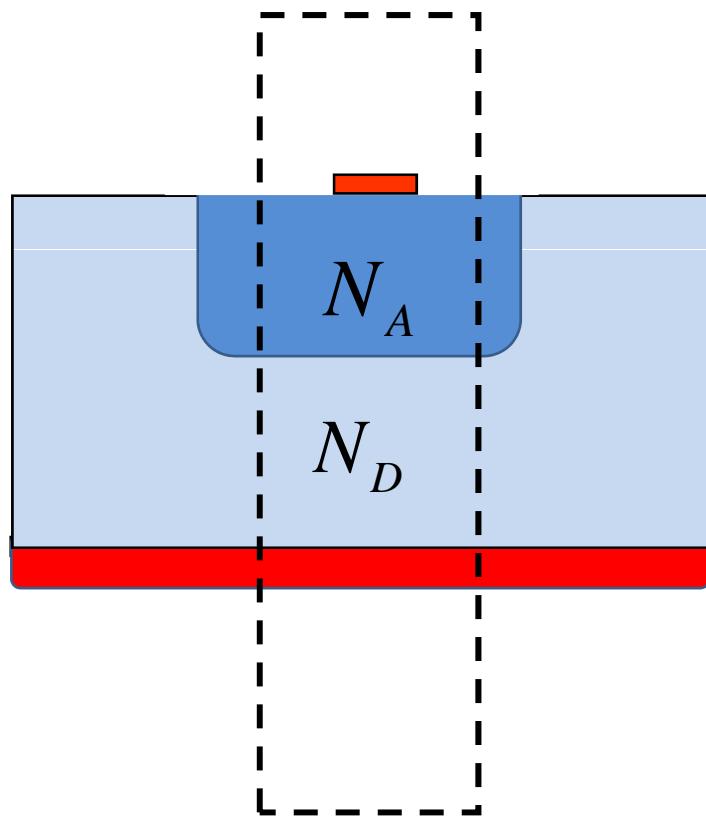


GaN lasers

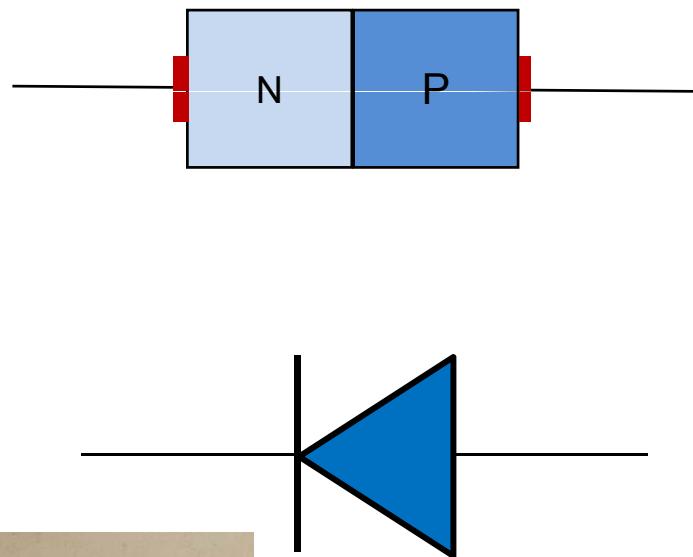


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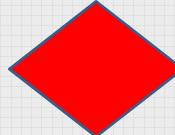
# p-n Junction Devices ...



Symbols



# Topic Map

	Equilibrium	DC	Small signal	Large Signal	Circuits
Diode					
Schottky					
BJT/HBT					
MOS					

# Drawing Band Diagram in Equilibrium...

$$\nabla \bullet D = q(p - n + N_D^+ - N_A^-)$$

$$\frac{\partial n}{\partial t} = \frac{1}{q} \nabla \bullet \mathbf{J}_N - r_N + g_N$$

$$\mathbf{J}_N = qn\mu_N E + qD_N \nabla n$$

$$\frac{\partial p}{\partial t} = \frac{-1}{q} \nabla \bullet \mathbf{J}_P - r_P + g_P$$

$$\mathbf{J}_P = qp\mu_P E - qD_P \nabla p$$

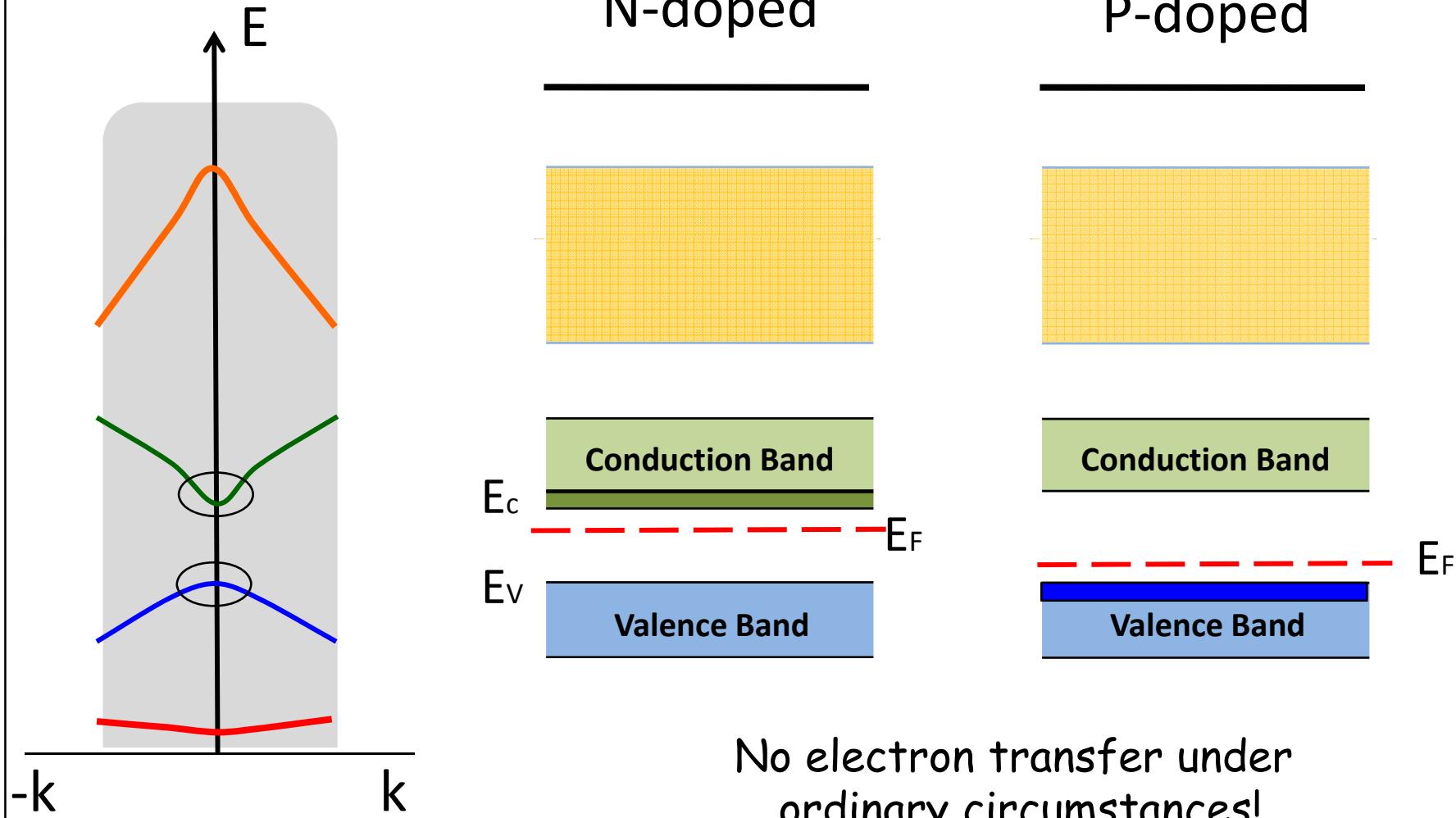
← equilibrium

DC  $dn/dt=0$

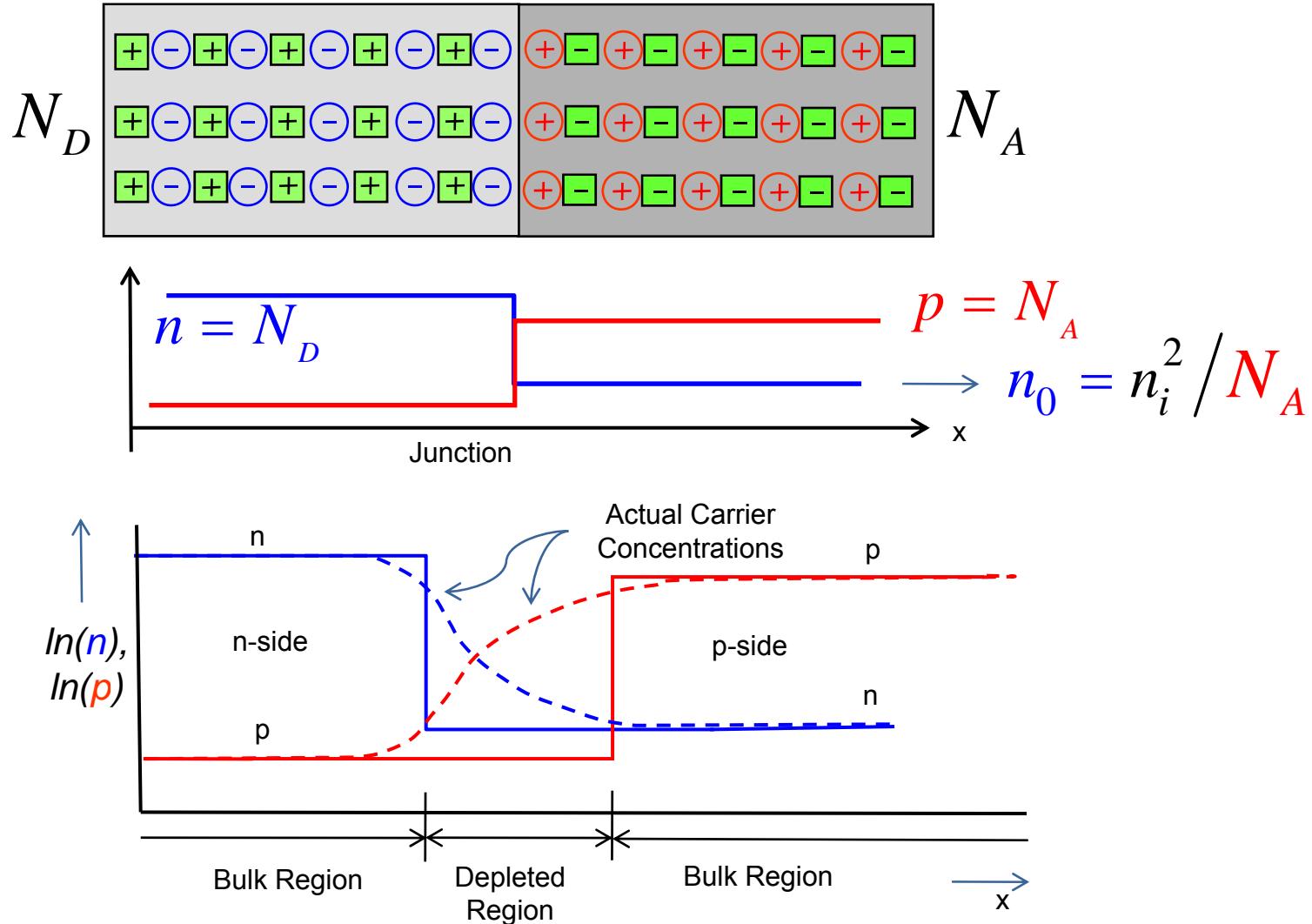
Small signal  $dn/dt \sim j\omega t \times n$

Transient --- full solution

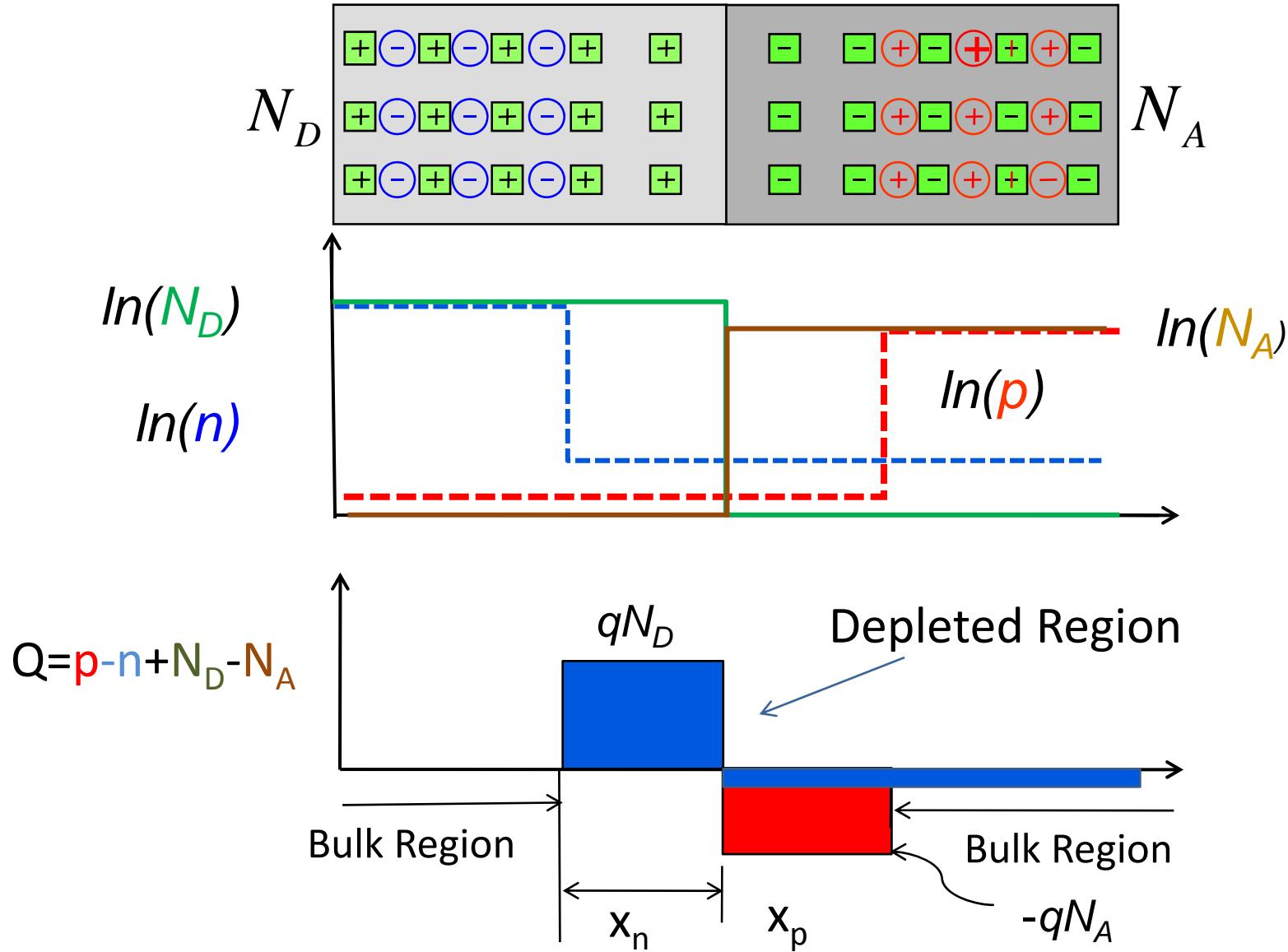
# P and N doped Material Side by Side ...



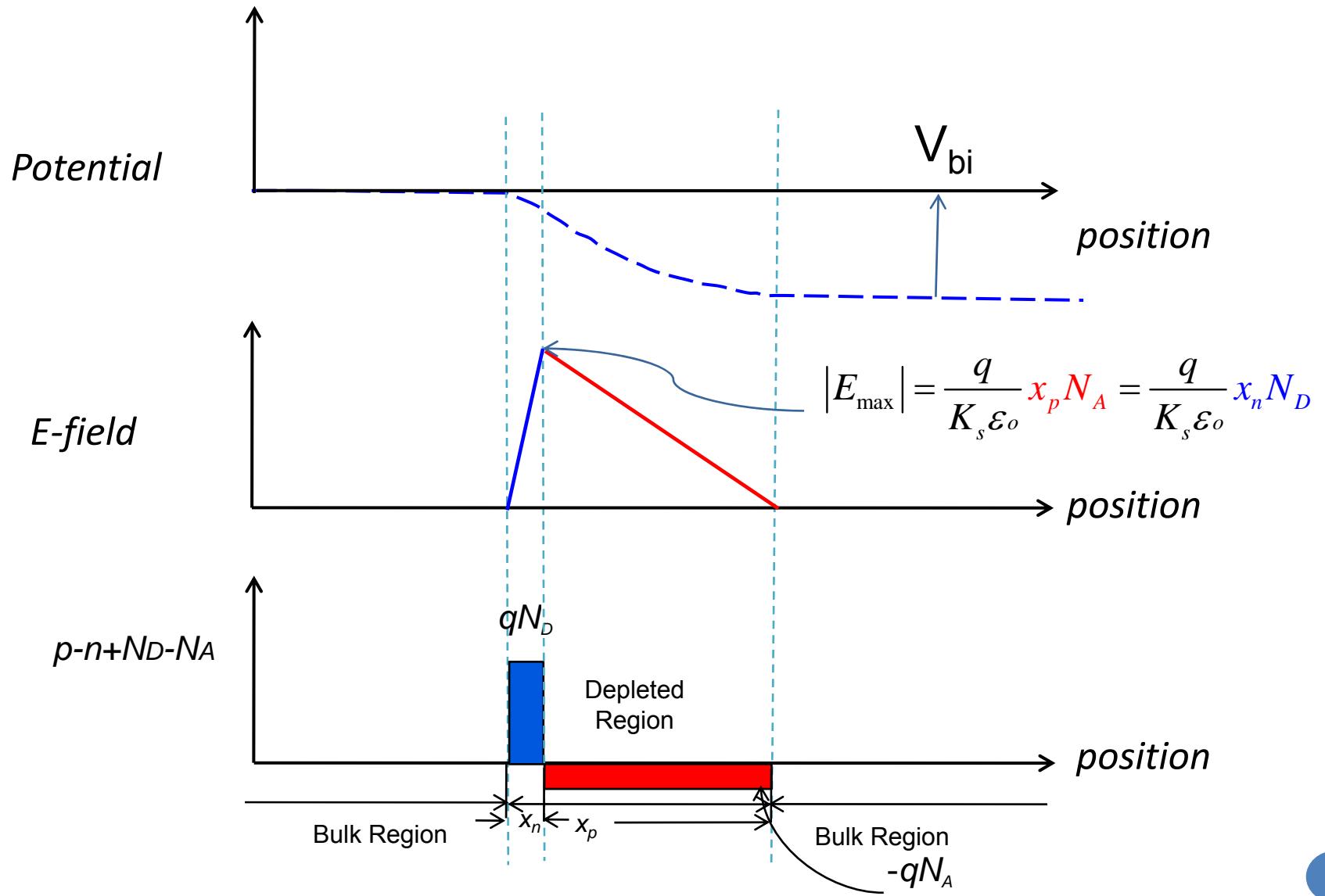
# Forming a Junction



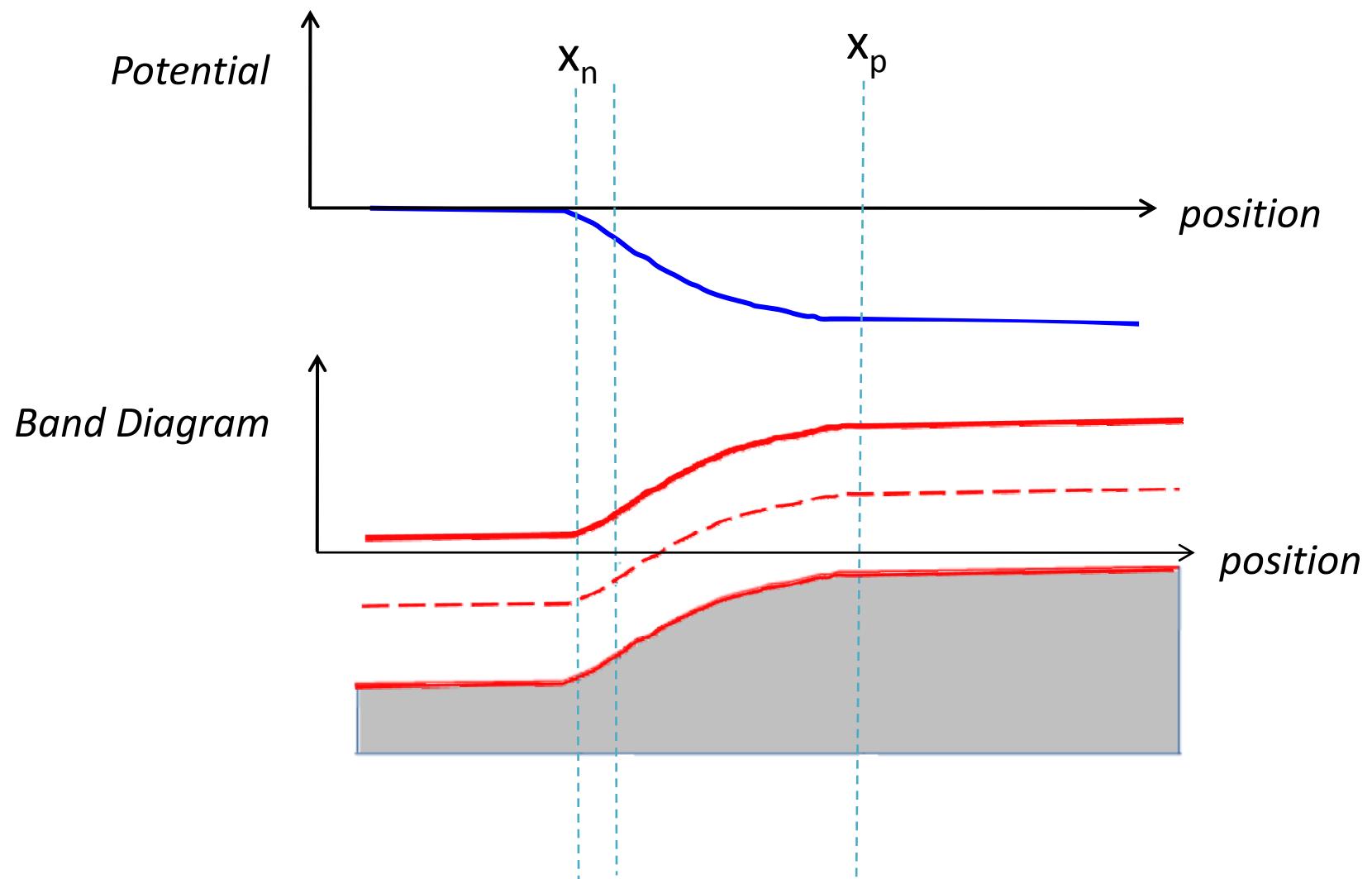
# Formation of a Junction



# Sketch of Electrostatics



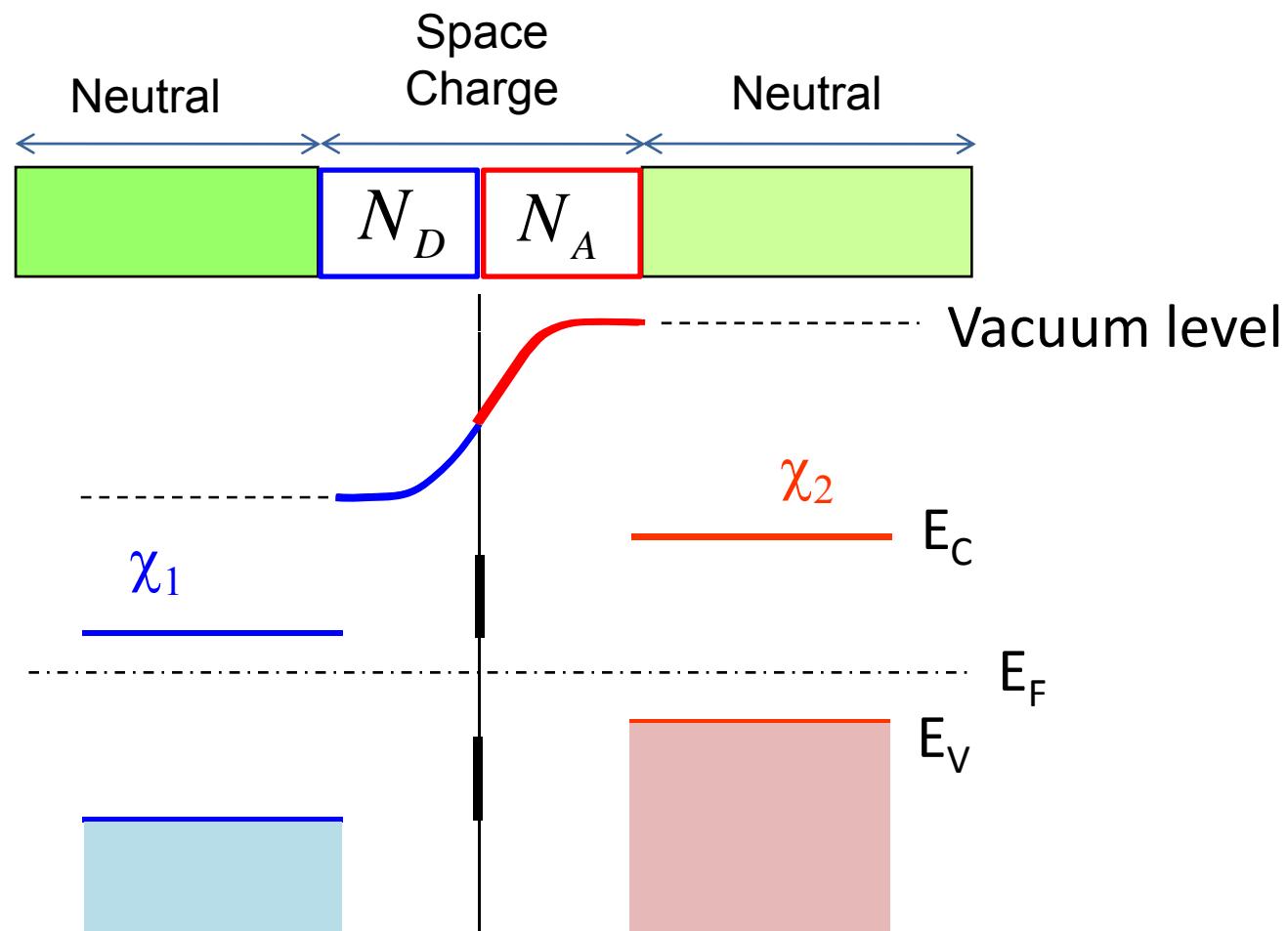
# Sketch of Electrostatics



# Outline

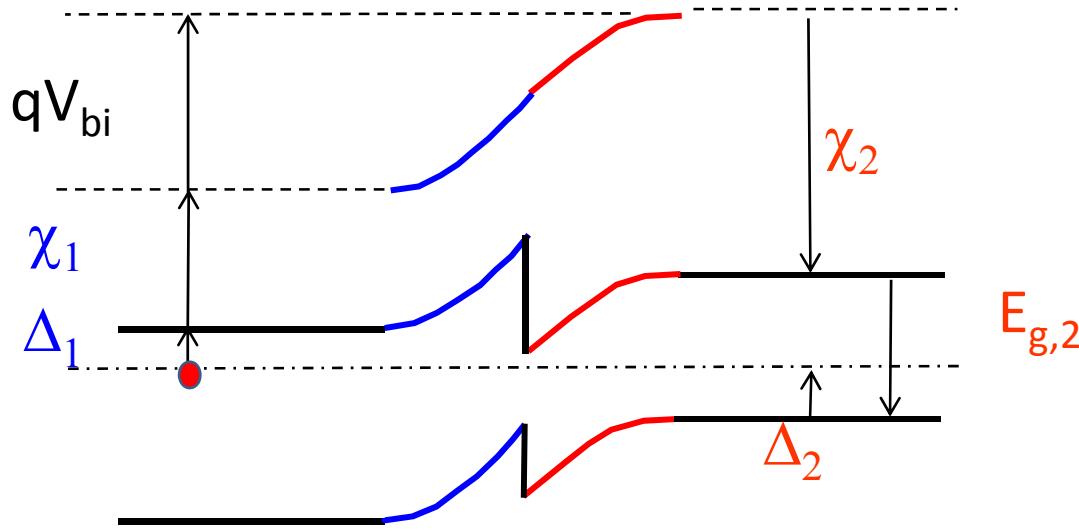
- 1) Introduction to p-n junctions
- 2) **Drawing band-diagrams**
- 3) Analytical solution in equilibrium
- 4) Band-diagram with applied bias

# Short-cut to Band-diagram



... is equivalent to solving the Poisson equation

# Built-in Potential: boundary conditions @infinity



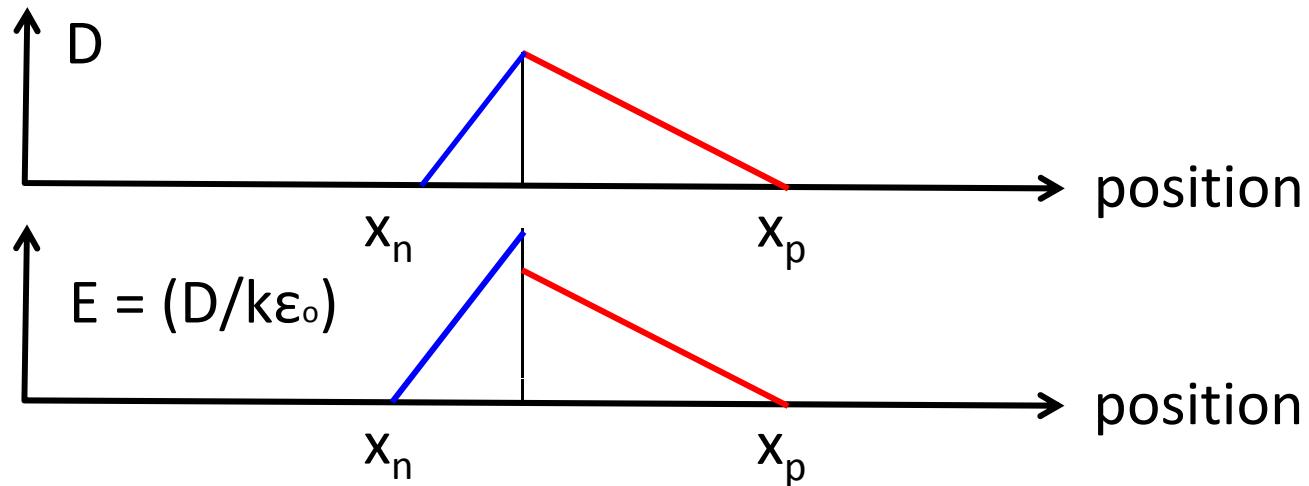
$$\Delta_1 + \chi_1 + qV_{bi} = \chi_2 + E_{g,2} - \Delta_2$$

$$qV_{bi} = E_{g,2} - \Delta_2 - \Delta_1 + \chi_2 - \chi_1$$

$$= \left( E_{g,2} + k_B T \ln \frac{N_A}{N_{V,2}} \right) + k_B T \ln \frac{N_D}{N_{C,1}} + (\chi_2 - \chi_1)$$

$$= k_B T \ln \frac{N_A N_D}{N_{V,2} N_{C,1} e^{-E_{g,2}/k_B T}} + (\chi_2 - \chi_1)$$

# Interface Boundary Conditions

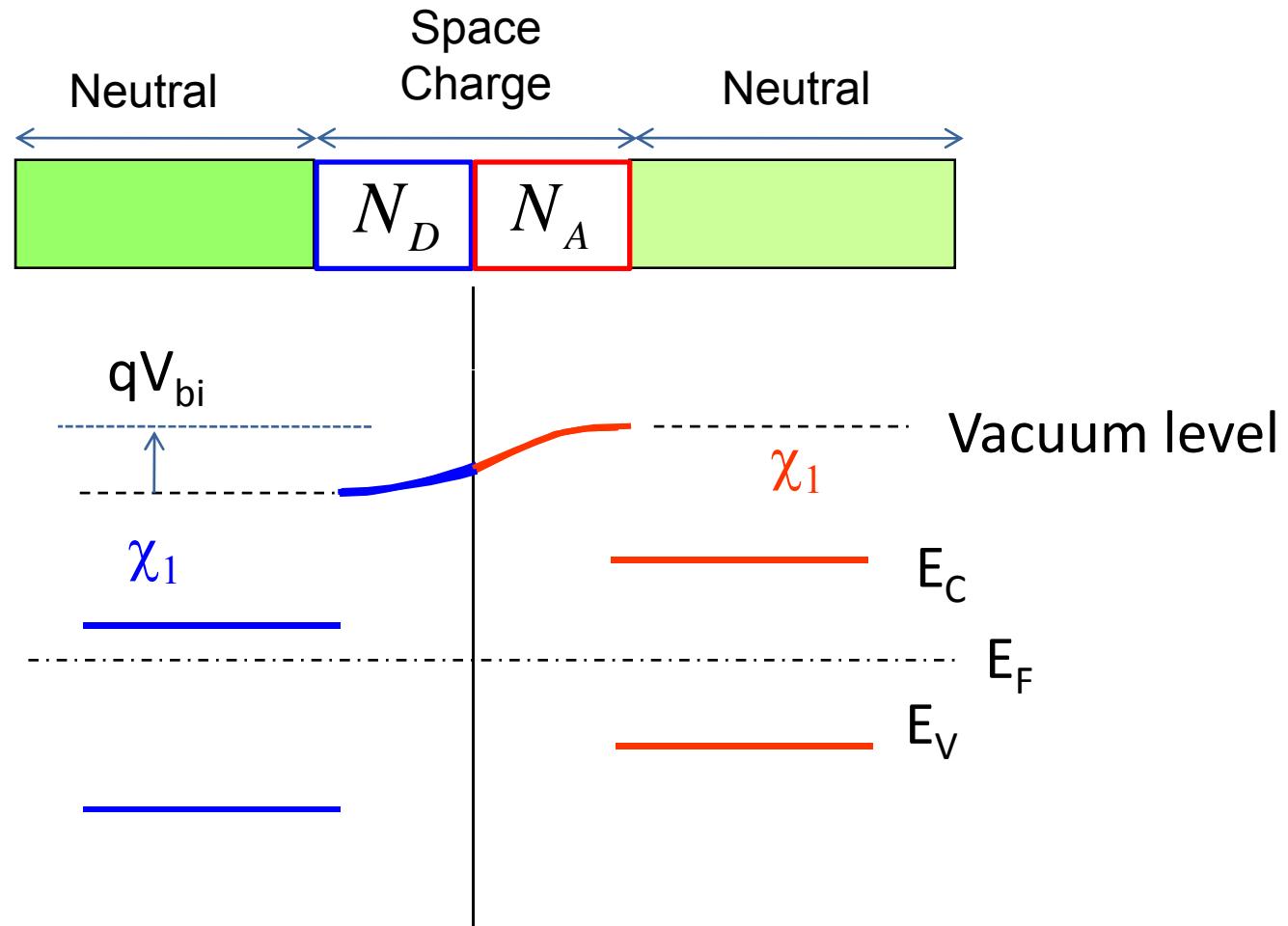


$$D_1 = K_1 \epsilon_0 E(0^-) = K_2 \epsilon_0 E(0^+) = D_2$$

$$E(0^-) = \frac{K_2}{K_1} E(0^+)$$

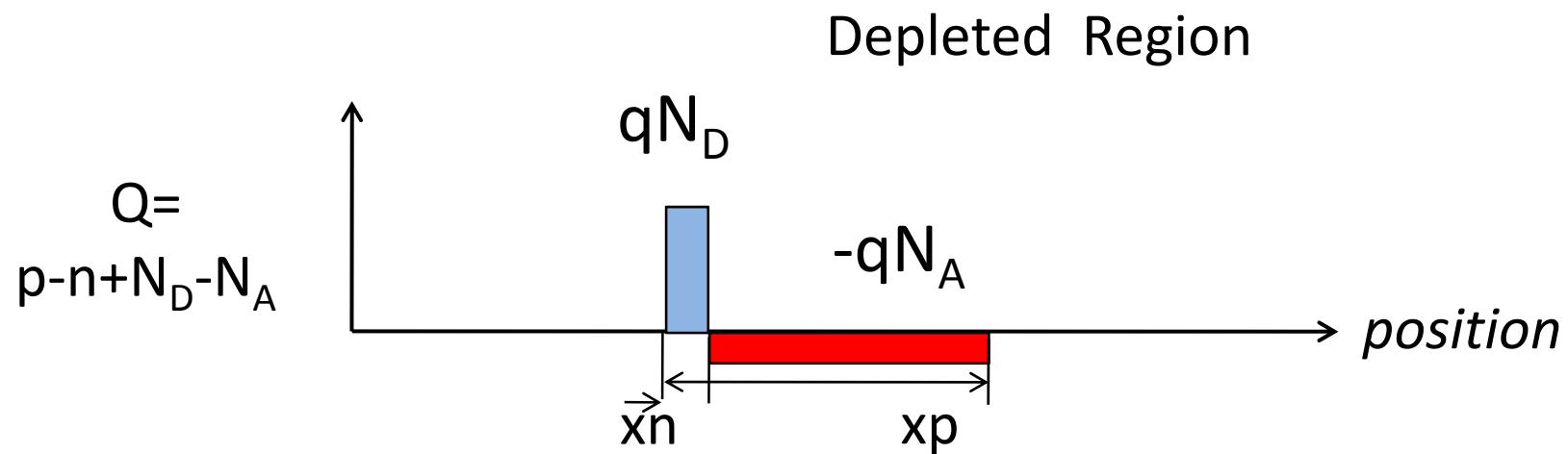
Displacement is continuous across the interface, field need not be ..

# Built-in voltage for **Homo**-junctions



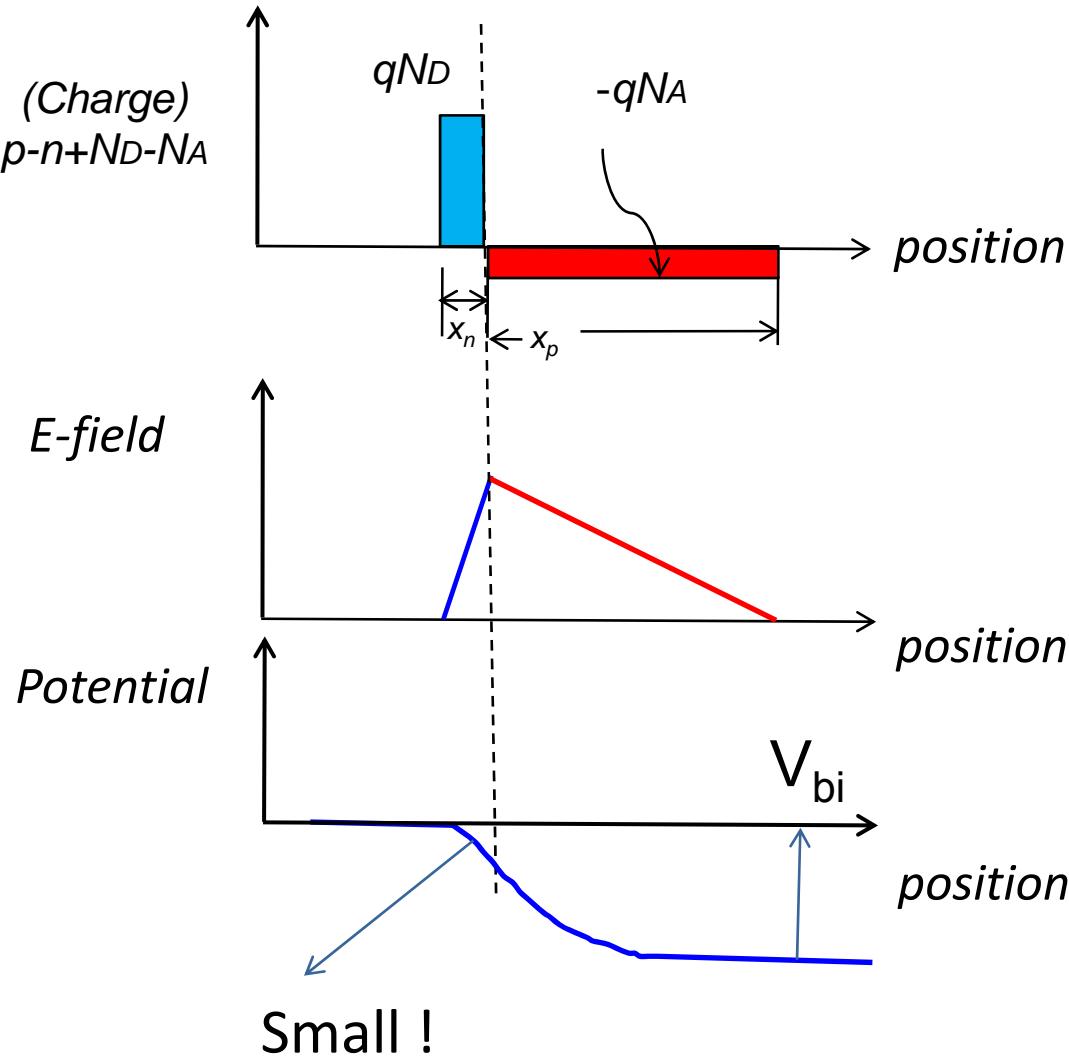
$$qV_{bi} = k_B T \ln \frac{N_A N_D}{N_{V,2} N_{C,1} e^{-E_{g,2}/k_B T}} + (\chi_2 - \chi_1) = k_B T \ln \frac{N_A N_D}{N_V N_C e^{-E_g/k_B T}} = k_B T \ln \frac{N_A N_D}{n_i^2}$$

# Analytical Solution of Poisson Equation



$$K_S \epsilon_0 \frac{d^2 V}{dx^2} = -q(p - n + N_D^+ - N_A^-)$$

# Analytical Solution for Homojunctions



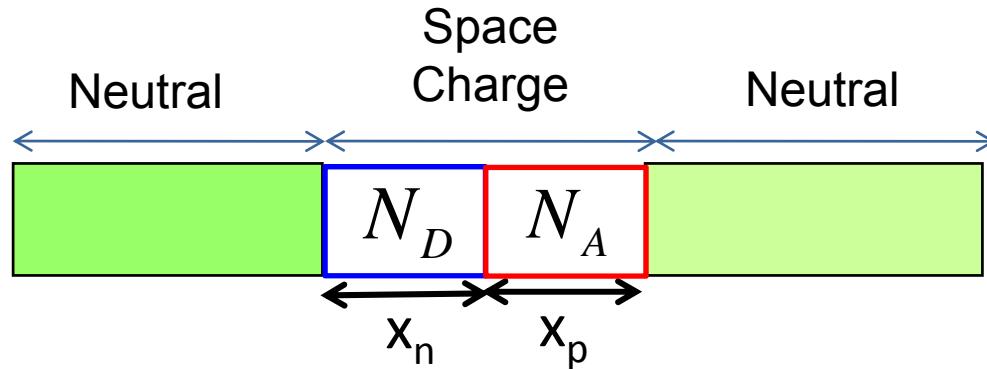
$$E(0^-) = \frac{qN_D x_n}{k_s \epsilon_0}$$

$$E(0^+) = \frac{qN_A x_p}{k_s \epsilon_0}$$

$$\Rightarrow N_D x_n = N_A x_p$$

$$\begin{aligned} qV_{bi} &= \frac{E(0^-)x_n}{2} + \frac{E(0^+)x_p}{2} \\ &= \frac{qN_D x_n^2}{2k_s \epsilon_0} + \frac{qN_A x_p^2}{2k_s \epsilon_0} \end{aligned}$$

# Depletion Regions in Homojunctions

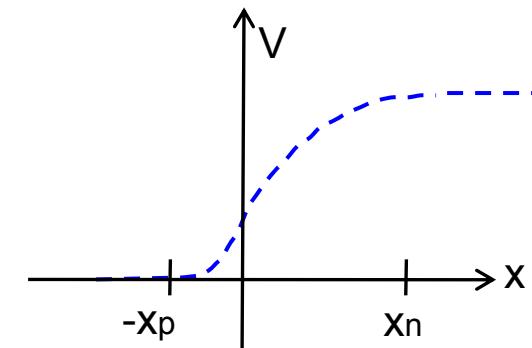
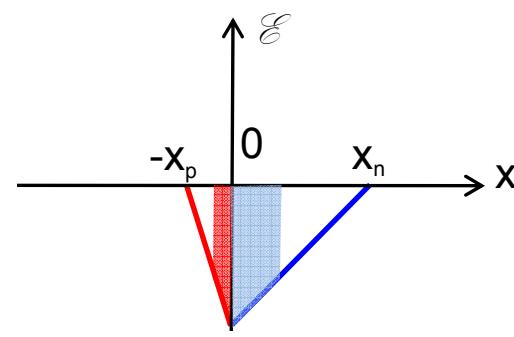
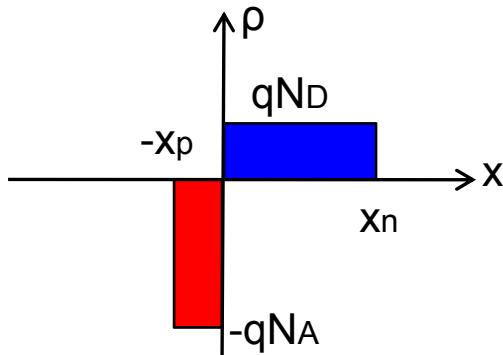
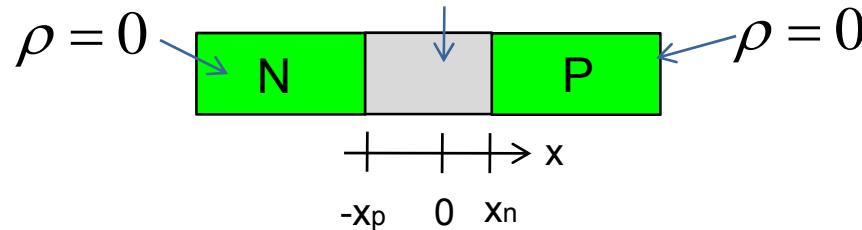


$$\left. \begin{aligned} N_D x_n &= N_A x_p \\ q V_{bi} &= \frac{q N_D x_n^2}{2 k_s \epsilon_0} + \frac{q N_A x_p^2}{2 k_s \epsilon_0} \end{aligned} \right\} \quad \begin{aligned} x_n &= \sqrt{\frac{2 k_s \epsilon_0}{q} \frac{N_A}{N_D (N_A + N_D)} V_{bi}} \\ x_p &= \sqrt{\frac{2 k_s \epsilon_0}{q} \frac{N_D}{N_A (N_A + N_D)} V_{bi}} \end{aligned}$$

HW: Solve the same problem for a hetero-junction

# Complete Analytical Solution

$$\rho = q(N_D - N_A)$$



$$\frac{d\mathcal{E}}{dx} = \begin{cases} \frac{-qN_A}{K_s \epsilon_0} & \dots \dots \dots -x_p \leq x \leq 0 \\ \frac{qN_D}{K_s \epsilon_0} & \dots \dots \dots 0 \leq x \leq x_n \\ 0 & \dots \dots \dots x \leq -x_p, x \geq x_n \end{cases}$$

$$\int_0^{\mathcal{E}(x)} d\mathcal{E}' = - \int_{-x_p}^x \frac{qN_A}{K_s \epsilon_0} dx'$$

$$\mathcal{E}(x) = - \frac{qN_A}{K_s \epsilon_0} (x_p + x) \dots \dots \dots -x_p \leq x \leq 0$$

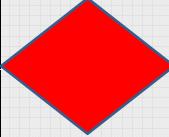
$$\int_{\mathcal{E}(x)}^0 d\mathcal{E}' = \int_x^{x_n} \frac{qN_D}{K_s \epsilon_0} dx'$$

$$\mathcal{E}(x) = - \frac{qN_D}{K_s \epsilon_0} (x_n - x) \dots \dots \dots 0 \leq x \leq x_n$$

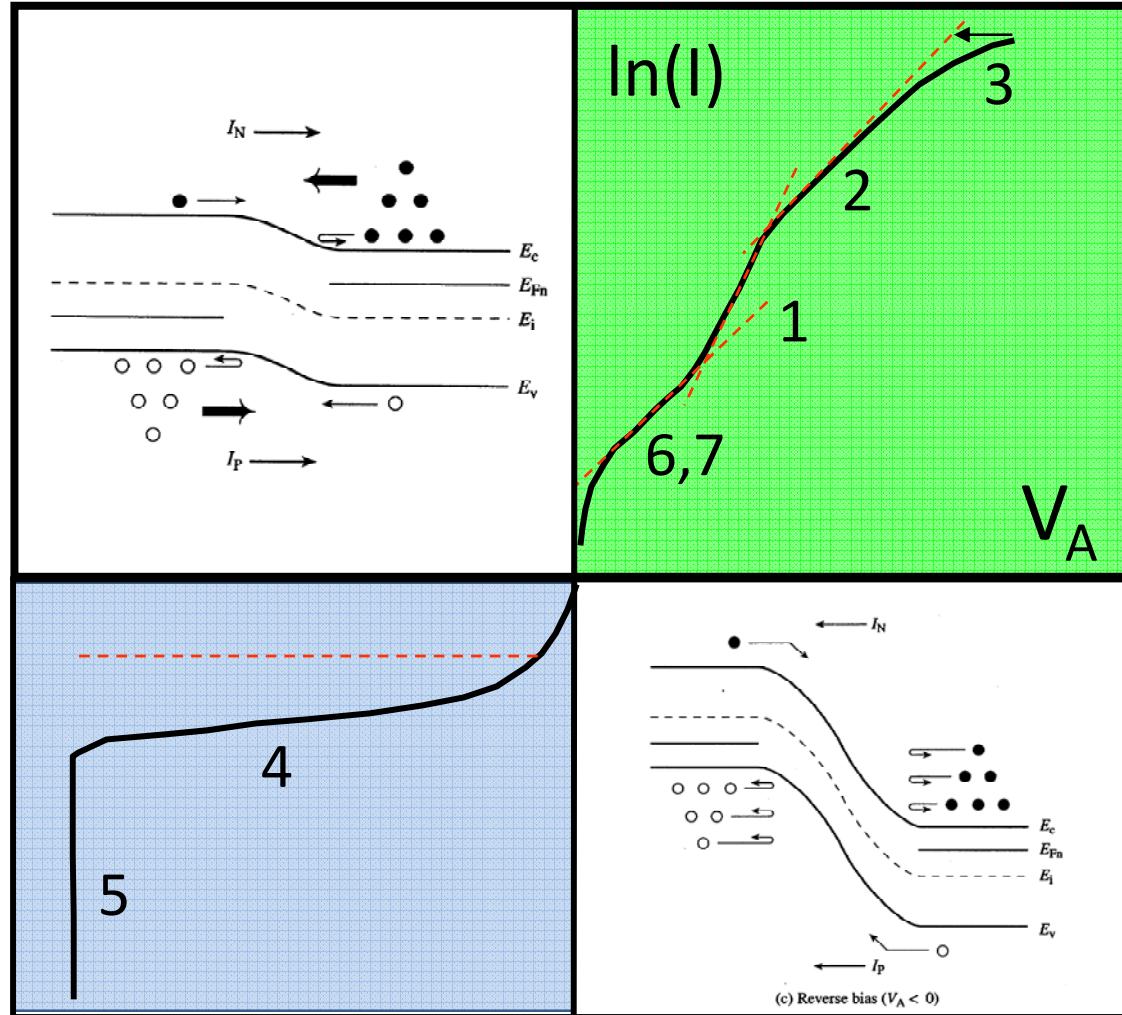
# Outline

- 1) Introduction to p-n junction transistors
- 2) Drawing band-diagrams
- 3) Analytical solution in equilibrium
- 4) Band-diagram with applied bias**

# Topic Map

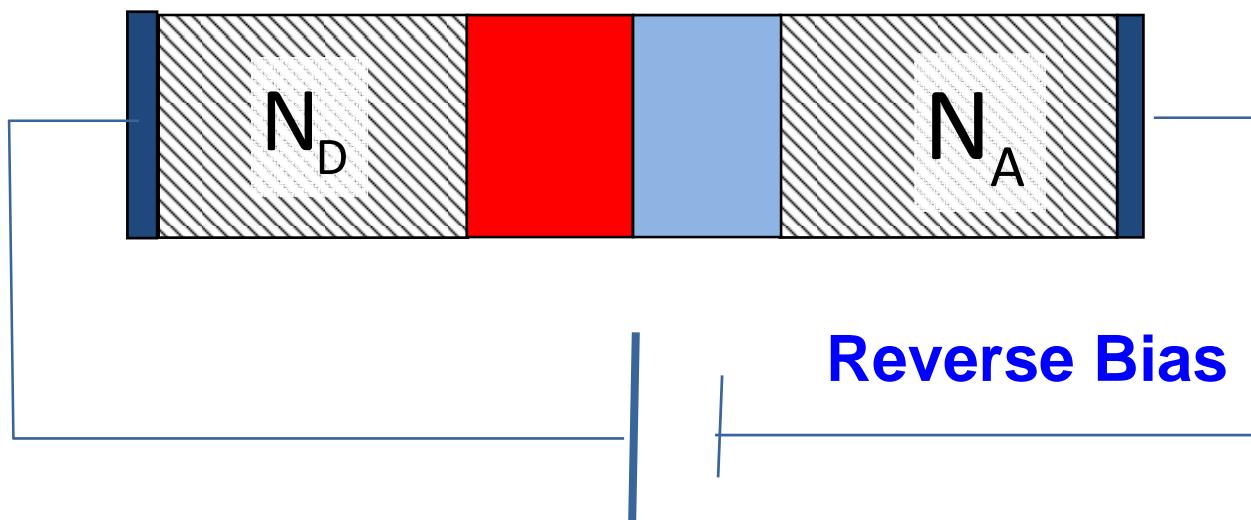
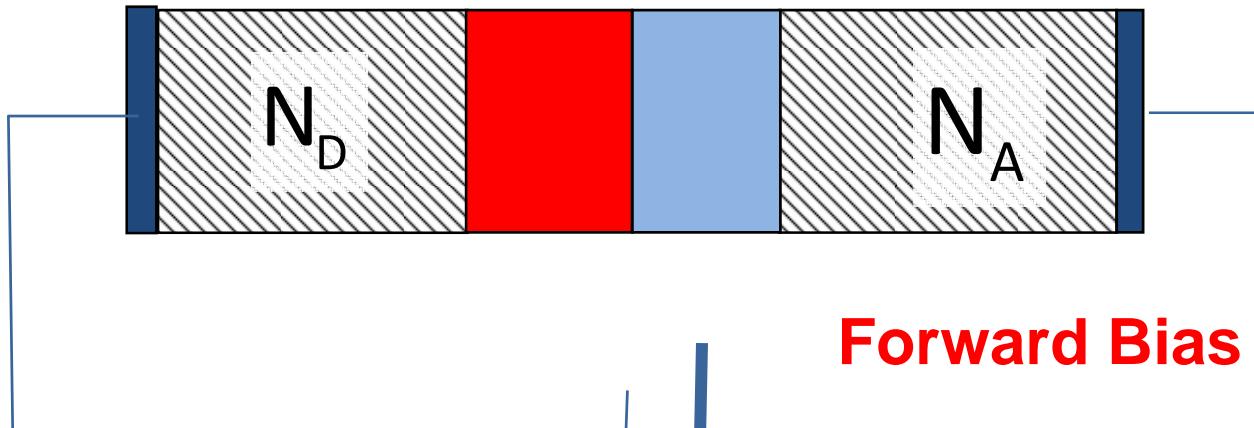
	Equilibrium	DC	Small signal	Large Signal	Circuits
Diode					
Schottky					
BJT/HBT					
MOS					

# Applying Bias to p-n Junction



1. *Diffusion limited*
2. *Ambipolar transport*
3. *High injection*
4. *R-G in depletion*
5. *Breakdown*
6. *Trap-assisted R-G*
7. *Esaki Tunneling*

# Forward and Reverse Bias

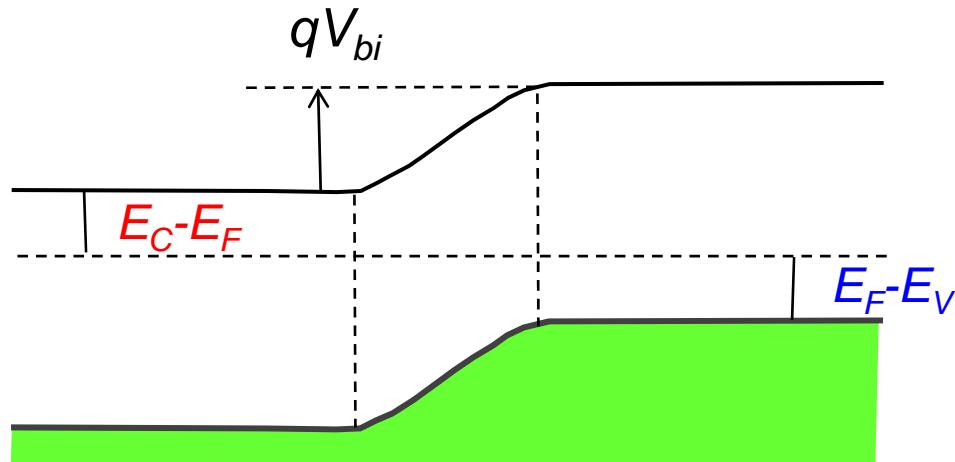


# Band Diagram with Applied Bias...

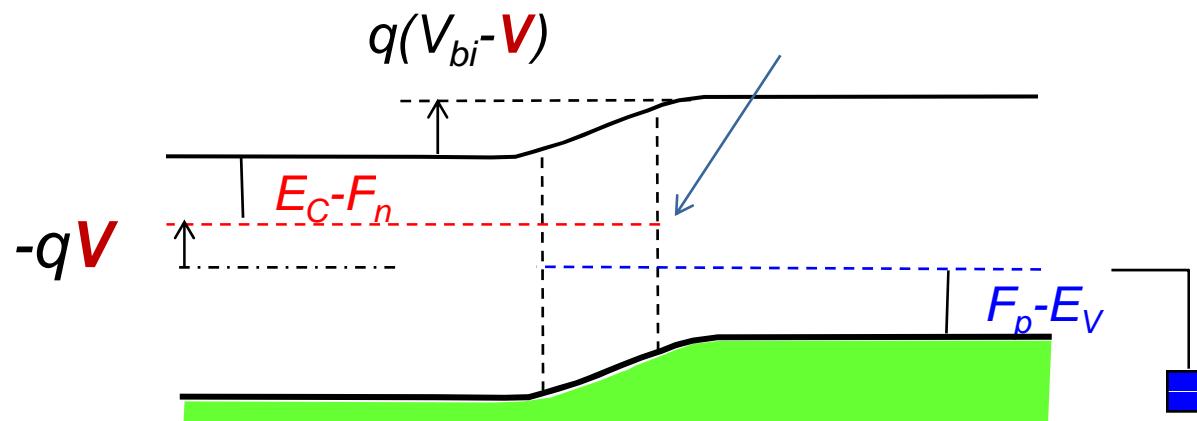
$$\nabla \bullet D = q(p - n + N_D^+ - N_A^-) \quad \text{Band diagram (now) ...}$$
$$\frac{\partial n}{\partial t} = \frac{1}{q} \nabla \bullet \mathbf{J}_N - r_N + g_N$$
$$\mathbf{J}_N = qn\mu_N E + qD_N \nabla n$$
$$\frac{\partial p}{\partial t} = -\frac{1}{q} \nabla \bullet \mathbf{J}_P - r_P + g_P$$
$$\mathbf{J}_P = qp\mu_P E - qD_P \nabla p$$

Next class ...

# Applying a Bias: Poisson Equation



Max value of  $V_{bi}$ ?

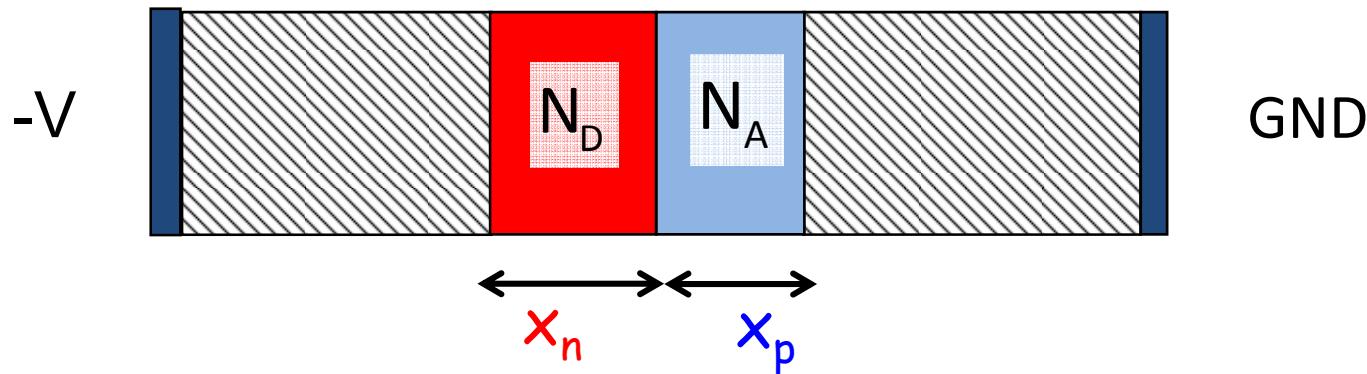


$$n(x) = n_i e^{(F_n - E_i)\beta}$$

$$p(x) = n_i e^{-(F_p - E_i)\beta}$$

$$n \times p = n_i^2 e^{(F_n - F_p)\beta}$$

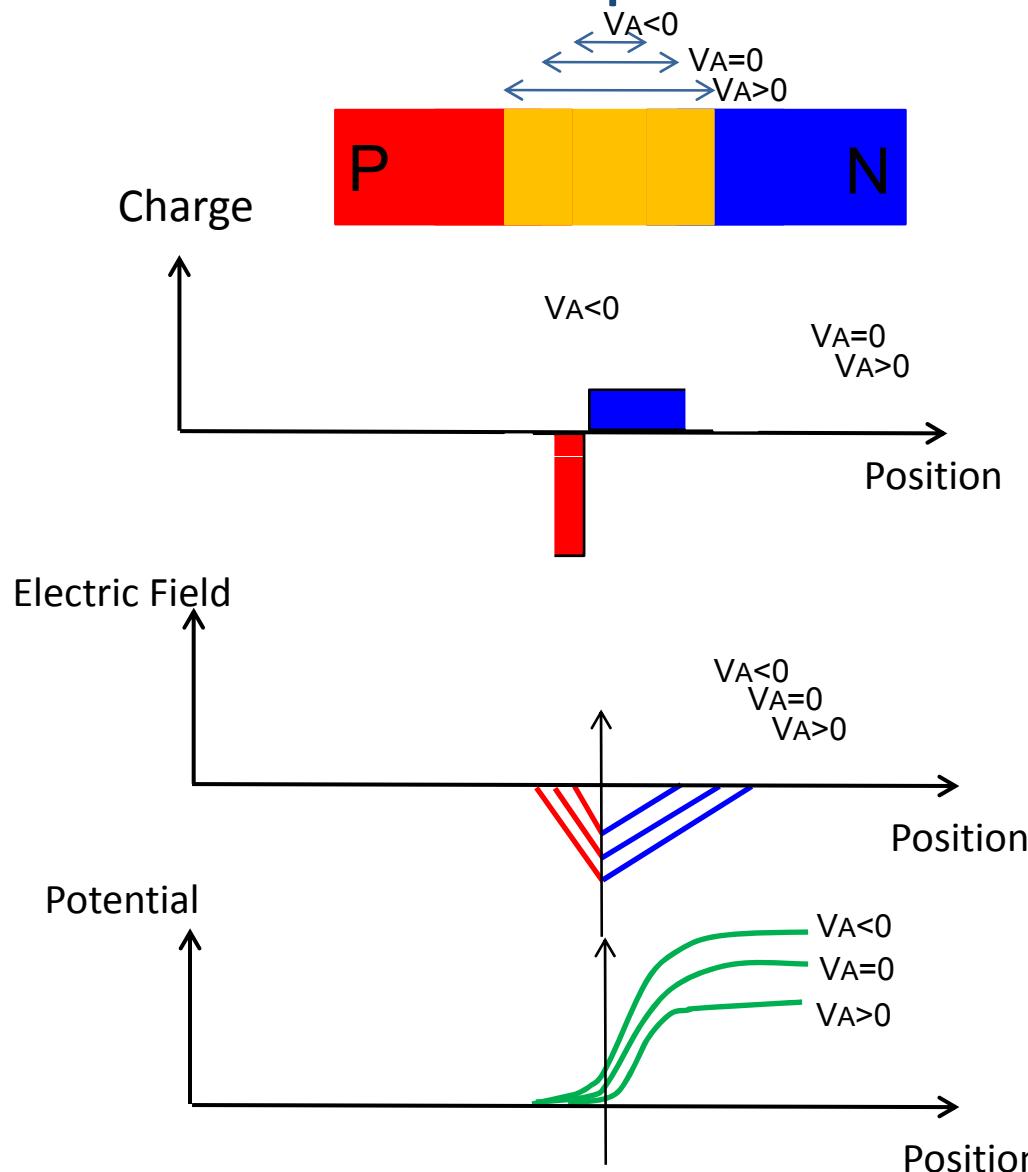
# Depletion Widths



$$\left. \begin{aligned} N_D x_n &= N_A x_p \\ q(V_{bi} - V) &= \frac{qN_D x_n^2}{2k_s \epsilon_0} + \frac{qN_A x_p^2}{2k_s \epsilon_0} \end{aligned} \right\} \begin{aligned} x_n &= \sqrt{\frac{2k_s \epsilon_0}{q} \frac{N_A}{N_D(N_A + N_D)} (V_{bi} - V)} \\ x_p &= \sqrt{\frac{2k_s \epsilon_0}{q} \frac{N_D}{N_A(N_A + N_D)} (V_{bi} - V)} \end{aligned}$$

What about heterojunctions?

# Fields and Depletion at Forward/Reverse Biases



Barrier height is reduced at forward biases

Significant increase of peak field at reverse bias ...

# Conclusion

- 1) Learning to draw band-diagram is one of the most important topic you learn in this course. Band-diagram is a graphical way of quickly solving Poisson equation.
- 2) If you consistently follow the rules of drawing band-diagrams, you will always get correct results. Try to follow the rules, not guess the final result.